

NPN Triple Diffused Planar Silicon Transistor

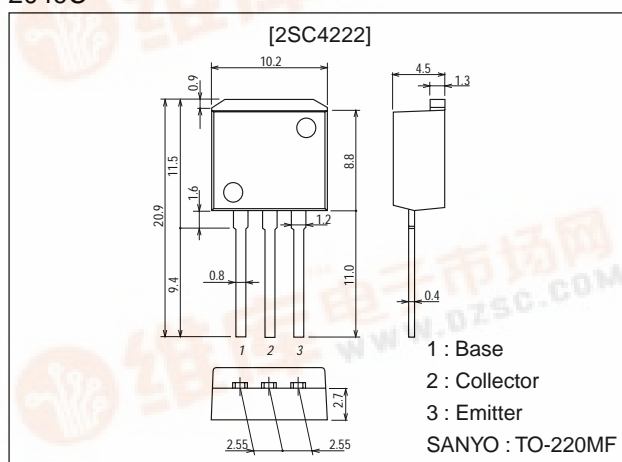
SANYO**2SC4222****500V/5A Switching Regulator Applications****Features**

- High breakdown voltage, high reliability.
- Fast switching speed ($t_f=0.1\mu s$ typ).
- Wide ASO.
- Adoption of MBIT process.
- Suitable for sets whose height is restricted.

Package Dimensions

unit:mm

2049C

**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ C$**

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		800	V
Collector-to-Emitter Voltage	V_{CEO}		500	V
Emitter-to-Base Voltage	V_{EBO}		7	V
Collector Current	I_C		5	A
Collector Current (Pulse)	I_{CP}	$PW \leq 300\mu s$, duty cycle $\leq 10\%$	10	A
Base Current	I_B		2	A
Collector Dissipation	P_C	$T_a = 25^\circ C$	1.65	W
		$T_c = 25^\circ C$	50	W
Junction Temperature	T_J		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Electrical Characteristics at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=500V$, $I_E=0$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=5V$, $I_C=0$			10	μA
DC Current Gain	h_{FE1}	$V_{CE}=5V$, $I_C=0.6A$	15*		50*	
	h_{FE2}	$V_{CE}=5V$, $I_C=3A$	8			

* : The h_{FE1} of the 2SC4222 is classified as follows. When specifying the h_{FE1} rank, specify two ranks or more in principle.

15	L	30	20	M	40	30	N	50
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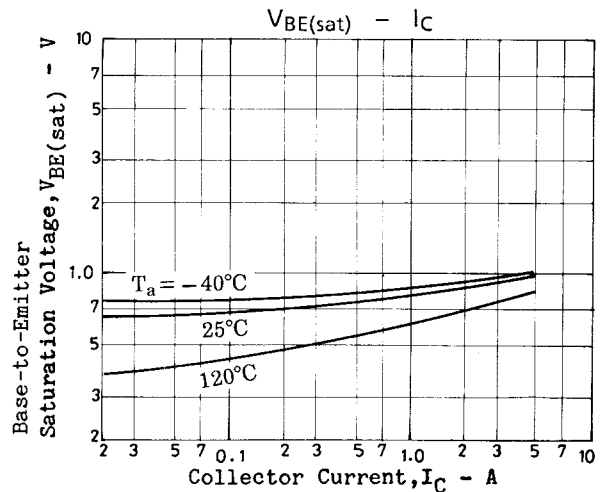
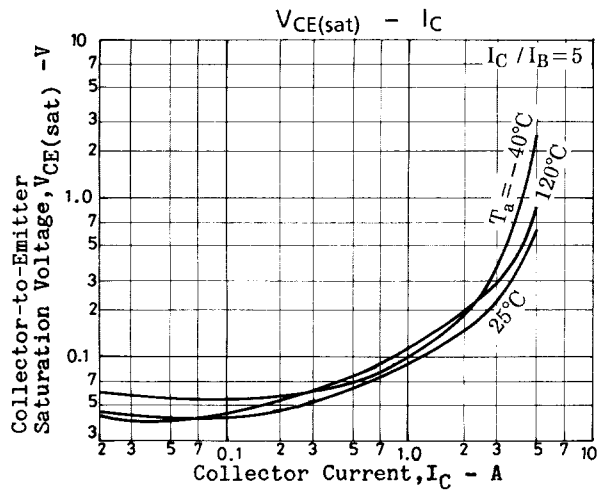
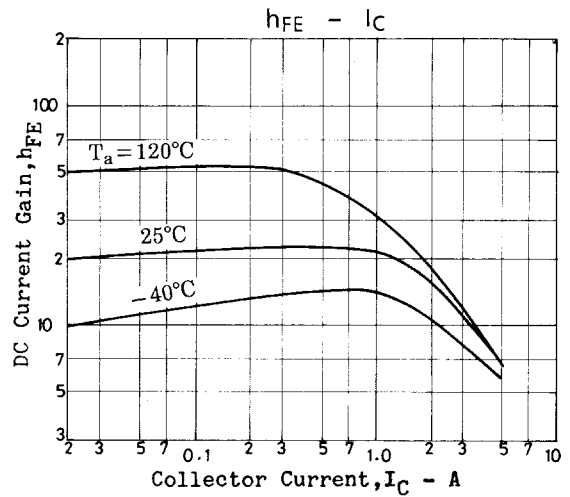
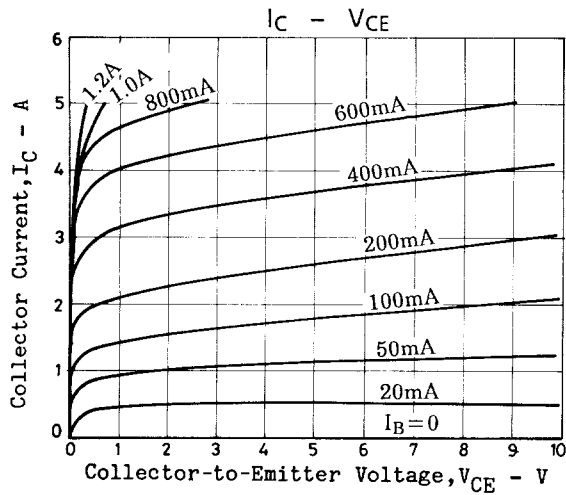
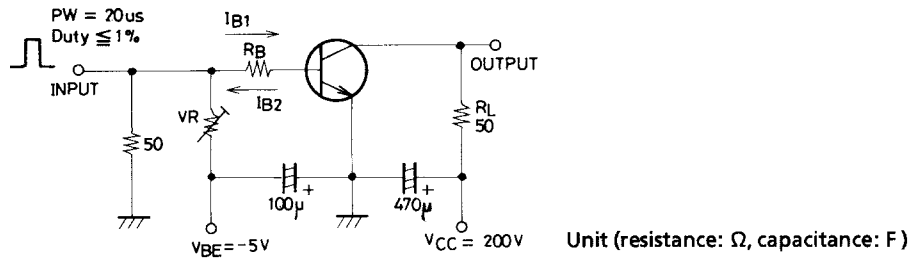
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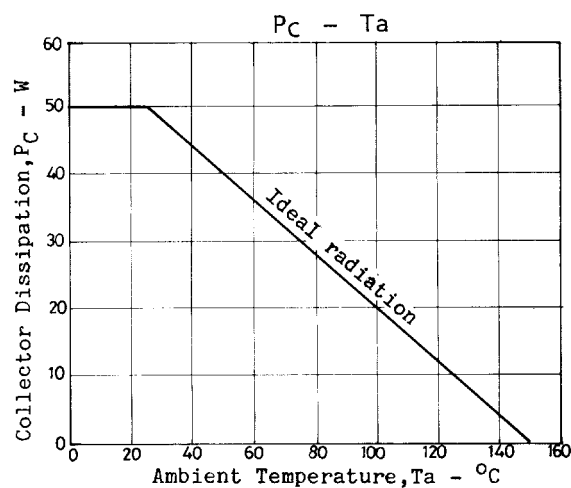
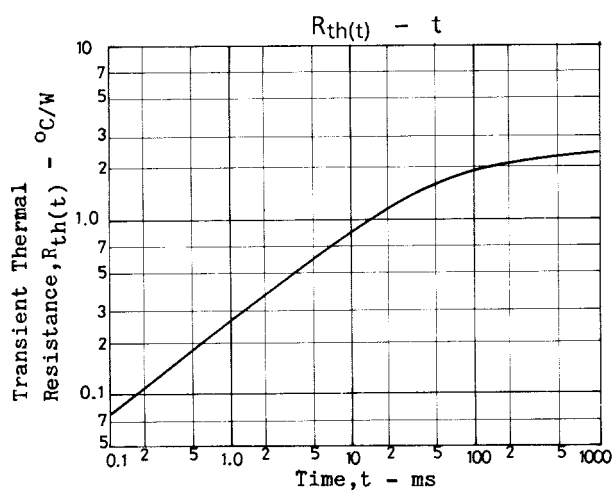
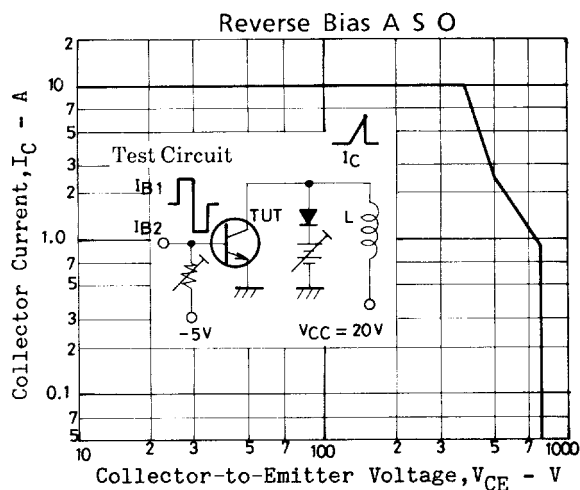
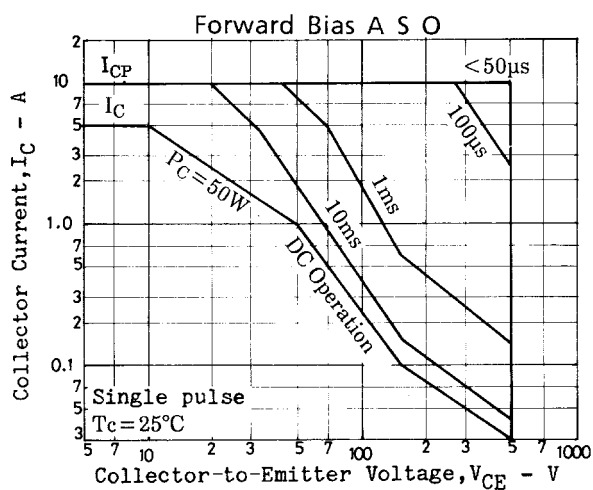
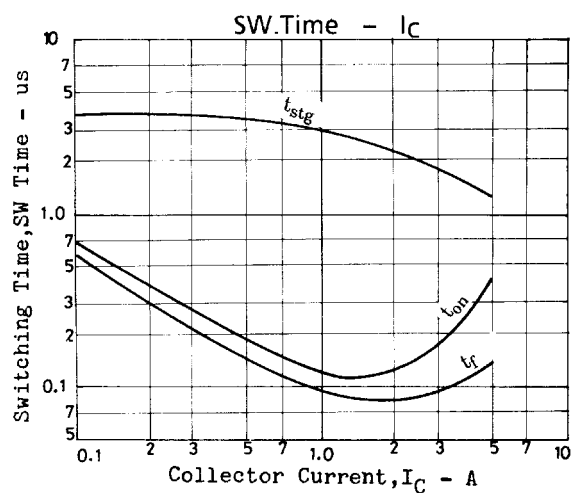
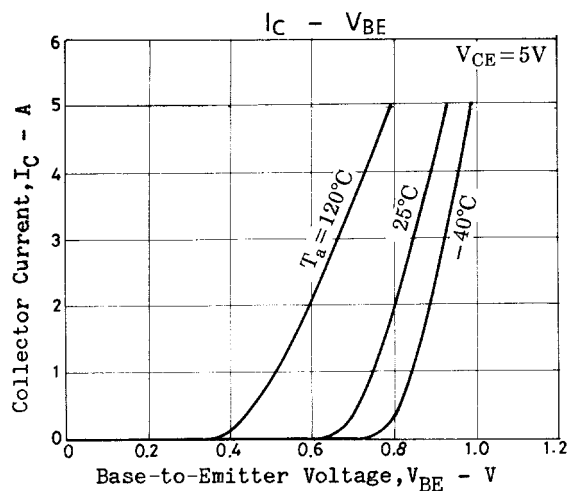
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=0.6A$		18		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		80		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=3A, I_B=0.6A$			1.0	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=3A, I_B=0.6A$			1.5	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=1mA, I_E=0$	800			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=5mA, R_{BE}=\infty$	500			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=1mA, I_C=0$	7			V
Collector-to-Emitter Sustain Voltage	$V_{CEO(sus)}$	$I_C=5A, I_B=1A, L=50\mu H$	500			V
	$V_{CEX(sus)}$	$I_C=2.5A, I_{B1}=-I_{B2}=1A, L=1mH, \text{clamped}$	500			V
Turn-ON Time	t_{on}	$I_C=4A, I_{B1}=0.8A, I_{B2}=-1.6A, R_L=50\Omega, V_{CC}=200V$			0.5	μs
Storage Time	t_{stg}	$I_C=4A, I_{B1}=0.8A, I_{B2}=-1.6A, R_L=50\Omega, V_{CC}=200V$			3.0	μs
Fall Time	t_f	$I_C=4A, I_{B1}=0.8A, I_{B2}=-1.6A, R_L=50\Omega, V_{CC}=200V$			0.3	μs

Switching Time Test Circuit



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